

## SBL2050CT thru 2060CT

# REVERSE VOLTAGE – 50 to 60 Volts FORWARD CURRENT – 20 Amperes

### SCHOTTKY BARRIER RECTIFIER

#### **FEATURES**

- Metal of silicon rectifier, majority carrier conduction
- · Guard ring for transient protection
- · Low power loss, high efficiency
- High current capability, low VF
- · High surge capability
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- IEC 61000-4-2, level 4 (ESD). > 15KV (air)

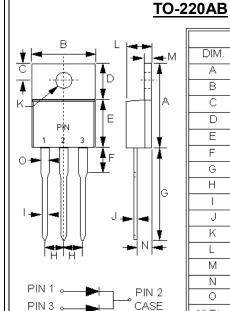
#### **MECHANICAL DATA**

• Case: JEDEC TO-220AB

• Polarity indicator: As marked on the body

Weight: 0.08 ounces, 2.24 gramsTerminals: Lead Free Plating

• Max. mounting torque = 0.5 N.m (5.1 Kgf-cm)



TO-220AB						
DIM.						
Α	14.22	15.88				
В	9.65	10.67				
С	2.54	3.43				
D	5.84	6.86				
Е	8.26	9.28				
F	-	6.35				
G	12.70	14.73				
Н	2.29	2.79				
I	0.51	1.14				
J	0.30	0.64				
K	3.53 ø	4.09 ø				
L	3.56	4.83				
М	1.14	1.40				
N	2.03	2.92				
0	1.14	1.50				
All Dimensions in millimeter						

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

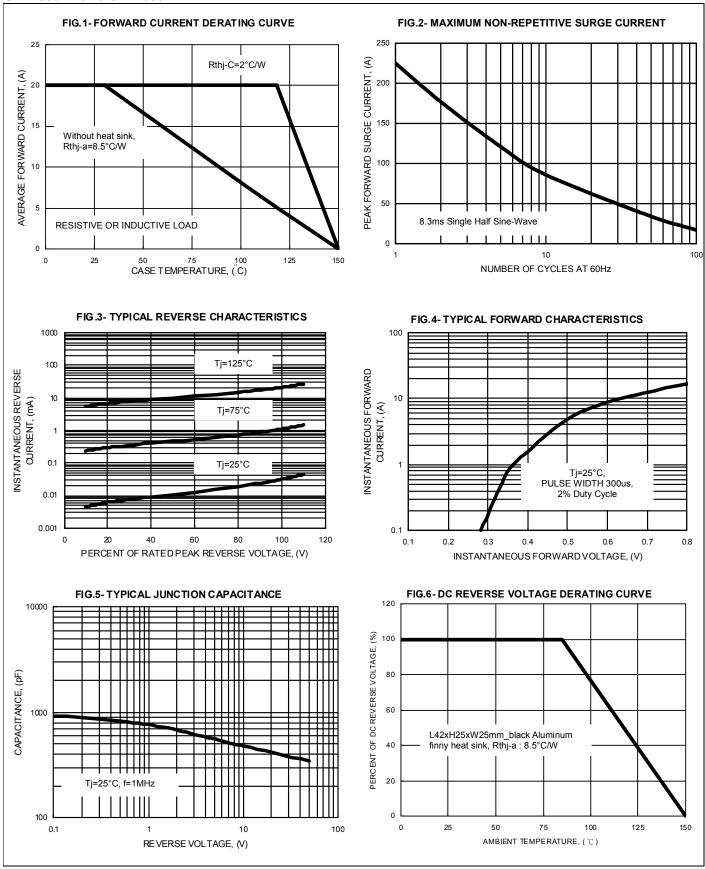
Ratings at 25°C ambient temperature unless otherwise specified.

PARAMETER			SYMBOL	SBL2050CT	SBL2060CT	UNIT
Device marking code			Note	SBL2050CT	SBL2060CT	
Maximum Repetitive Peak Reverse Voltage			$V_{RRM}$	50	60	V
Maximum RMS Voltage			V <sub>RMS</sub>	35	42	V
Maximum DC Blocking Voltage			$V_{DC}$	50	60	V
Average Rectified Output Current @TC=100°C		I <sub>F</sub>	20		А	
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load			I <sub>FSM</sub>	225		А
Typical Junction Capacitance per element (1)			CJ	600		РF
Storage temperature range			T <sub>STG</sub>	-55 to +150		°C
Operating junction temperature range			TJ	-55 to +150		°C
PARAMETER	TEST CO	TEST CONDITIONS		Min.	Max.	UNIT
Forward Voltage (2)	IF=10A	Tj=25°C	V <sub>F</sub>		0.75	V
Leakage Current (2)	VR=Rated	Tj=25°C Tj=100°C	I <sub>R</sub>		0.1 50	mA
THERMAL CHARACTERISTIC			SYMBOL	Typical		UNIT
Typical thermal resistance _ Junction to Case (3)			R⊕ <sub>JC</sub>	2.0		°C/W
Note :					REV. 5, Jul-2012, KTHC81	

(1) Measured at 1.0MHz and applied reverse voltage of 4.0 V<sub>DC</sub>.

- (2) 300us Pulse Width, 2% Duty Cycle.
- (3) Thermal Resistance Junction to Case. Device mounted on L42xH25xW25mm\_ black Aluminum finny heat sink.







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